

02-06-03

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## TRANSMITTAL OF FORMAL DRAWINGS

Docket No.  
BUR919990190US1 (13020)

In Re Application Of: Douglas Duane Coolbaugh, et al.

# 14  
with  
Form  
5-11-03

Serial No.

09/516,615

Filing Date

March 1, 2000

Confirmation No.

3878

Examiner

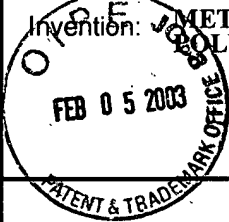
Cuong Quang Nguyen

Art Unit

2811

4-8-03

et al.

Invention: METHOD OF FABRICATING A POLYSILICON CAPACITOR UTILIZING FET AND BIPOLAR BASE  
POLYSILICON LAYERS

Address to:

Assistant Commissioner for Patents  
Washington, D.C. 20231RECEIVED  
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TECHNOLOGY CENTER 2800

Transmitted herewith are:

3 sheets of formal drawing(s) for this application.

☒ Each sheet of drawing indicates the identifying indicia suggested in 37 CFR Section 1.84(c).

Signature

Steven Fischman  
Registration No. 34,594SCULLY, SCOTT, MURPHY & PRESSER  
400 Garden City Plaza  
Garden City, New York 11530  
(516) 742-4343

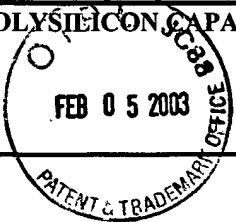
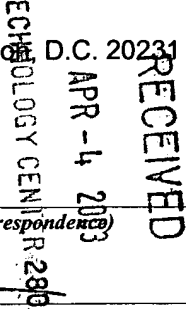
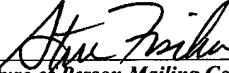
Dated: February 5, 2003

I certify that this document and attached formal drawings  
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Signature of Person Mailing Correspondence

Steven Fischman

Typed or Printed Name of Person Mailing Correspondence

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| <b>CERTIFICATE OF MAILING BY "EXPRESS MAIL" (37 CFR 1.10)</b>  |                                     |                                       | Docket No.<br><b>BUR919990190US1 (13020)</b> |
| Applicant(s): <b>Douglas Duane Coolbaugh, et al.</b>   |                                     |                                       |  |
| Serial No.<br><b>09/516,615</b>  | Filing Date<br><b>March 1, 2000</b> | Examiner<br><b>Cuong Quang Nguyen</b> | Group Art Unit<br><b>2811</b>                |
| Invention: <b>METHOD OF FABRICATING A POLYSILICON CAPACITOR UTILIZING FET AND BIPOLAR BASE POLYSILICON LAYERS</b>  |                                     |                                       |  |
|   |                                     |                                       |  |
| I hereby certify that the following correspondence:  |                                     |                                       |  |
| <b>Issue Fee Transmittal (in duplicate); "Fee Address" Indication Form (in duplicate); Change of Correspondence Address (in duplicate)</b>   |                                     |                                       |  |
| <i>(Identify type of correspondence)</i>   |                                     |                                       |  |
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| <div style="display: flex; justify-content: space-between;"><div><u>Steven Fischman</u><br/><i>(Typed or Printed Name of Person Mailing Correspondence)</i></div><div><br/><i>(Signature of Person Mailing Correspondence)</i></div></div> |                                     |                                       |  |
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